L Number	Hits	Search Text	DB	Time stamp
2	4751	(substrate with thickness) and temperature	USPAT;	2004/02/26 13:30
		and (gap) and (liquid adj crystal)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	2004/02/26 13:31
3	19	(substrate with thickness) and (room adj	USPAT;	2004/02/26 13:31
		<pre>temperature) and (gap near (icrease or decrease)) and (liquid adj crystal)</pre>	US-PGPUB; EPO; JPO;	
		decrease)) and (liquid ad) Clystal)	DERWENT;	
			IBM TDB	
4	58	((cell adj gap) and (thermal adj expans\$4))	USPAT;	2004/02/26 13:46
1		and (room adj temperature)	US-PGPUB;	
		,,,	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
6	60	((cell adj gap) near10 (increase or	USPAT;	2004/02/26 13:47
İ		decrease)) and (room adj temperature)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
7	43	((cell adj gap) and (thermal adj expans\$4))	USPAT;	2004/02/26 13:53
		same temperature	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	i
	202	340/155	USPAT	2002/06/26 20:45
-		349/155 349/155	USPAT; JPO	2002/06/26 20:43
-	1169 1118	349/153	USPAT; JPO	2002/06/24 16:32
-	176	349/190	USPAT; JPO	2002/06/24 16:33
	21	((cell adj gap) and (thermal adj expans\$4))	USPAT; JPO	2003/05/12 14:18
	21	same temperature	,	
_	8	(((cell adj gap) and (thermal adj expans\$4))	USPAT; JPO	2002/06/24 20:03
i	_	same temperature) and 349/155		i
-	193	349/155 and (cell adj gap)	USPAT; JPO	2002/06/26 14:23
-	47	349/190 and (cell adj gap)	USPAT; JPO	2002/06/24 21:03
-	115	349/153 and (cell adj gap)	USPAT; JPO	2002/06/24 21:04
-	1991	(liquid adj crystal) and (cell adj gap)	USPAT; JPO	2002/06/26 14:25
-	57	(liquid adj crystal) and ((cell adj gap)	USPAT; JPO	2002/06/26 14:26
ļ		same center)	110000	2002/06/26 20:46
-	179		USPAT USPAT	2002/06/26 20:46
	179	349/158 and (substrate with thickness) ((cell adj gap) and (thermal adj expans\$4))	USPAT;	2003/01/13 17:16
- '	121	and temperature	US-PGPUB;	2003/01/13 10:30
1		and temperature	JPO	
	166	349/158 and (substrate with thickness)and	USPAT;	2003/01/13 17:17
-	100	temperature	US-PGPUB;	,
			JPO	
_	36	349/158 and (substrate with thickness)and	USPAT;	2003/05/12 14:22
		temperature and gradua\$4	US-PGPUB;	
			JPO	
-	12451	(substrate with thickness) and temperature	USPAT;	2003/01/13 18:11
] [and gradua\$4	US-PGPUB;	
			JPO	
-	2079	(substrate with thickness) and temperature	USPAT;	2003/01/13 18:13
		and gradua\$4 and (liquid adj crystal)	US-PGPUB;	
			JPO	2002/01/14 10 22
-	1081	(substrate with thickness) and temperature	USPAT;	2003/01/14 10:32
		and gradua\$4 and (liquid adj crystal)and gap	US-PGPUB;	
	_	(muhabanta with thislenges) and tamparature	JPO USPAT;	2003/01/13 18:18
Į -	0	(substrate with thickness)and temperature and gradua\$4 and (liquid adj crystal)and gap	US-PGPUB;	2003/01/13 10:18
		and graduas4 and (liquid adj crystal)and gap and ((irregular with color) with	JPO	
.		temperature)	1350	
] _	10	(substrate with thickness) and temperature	USPAT;	2003/01/14 10:21
-	10	and gradua\$4 and (liquid adj crystal) and gap	US-PGPUB;	
1		and (irregular with temperature)	JPO	
_	29		USPAT;	2003/01/14 10:31
-	29	(substrate with thickness) and temperature and gradua\$4 and (liquid adj crystal) and gap	USPAT; US-PGPUB;	2003/01/14 10:31

-	127	(substrate with thickness) and temperature	USPAT;	2003/05/12 14:23
		and (gap same gradua\$4) and (liquid adj	US-PGPUB;	
		crystal)	JPO	
-	342	349/158 and (substrate with thickness)	USPAT;	2003/01/14 10:42
			US-PGPUB;	
			JPO	
-	37	((cell adj gap) and (thermal adj expans\$4))	USPAT;	2004/02/26 13:27
		same temperature	US-PGPUB;	
			EPO; JPO;	
	†		DERWENT;	i i
			IBM_TDB	/ /
-	140		USPAT;	2004/02/26 13:29
		and (gap same gradua\$4) and (liquid adj	US-PGPUB;	
		crystal)	EPO; JPO;	
			DERWENT;	
		240/450 2 /	IBM_TDB	2003/05/12 14:28
-	38	1	USPAT;	2003/05/12 14:28
		temperature and gradua\$4	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
			I DM I DB	L